Docket No.: F03-354-USDiv

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re patent application of

Hisaki KATO, et al.

FUJIT.044DIV

Serial No.: 10/634,836

Group Art Unit: 2822

Filed: August 6, 2003

Examiner: Keisha L. Rose

For:

LIGHT-EMITTING SEMICONDUCTOR DEVICE USING GALLIUM

NITRIDE COMPOUND SEMICONDUCTOR

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Sir:

Under the provisions of 37 CFR §1.97 through §1.99 and pursuant to applicants' duty of disclosure under 37 CFR §1.56, applicants respectfully bring the following documents, cited in the Japanese Office Action and listed on the attached form PTO-1449, to the attention of the Examiner in charge of the above-identified application. An English translation of the Japanese Office Action is enclosed. Copies of the listed documents are also provided herewith for the convenience of the Examiner.

In compliance with the requirements of 37 CFR §1.98(a)(3), as a concise statement of relevance, as it is presently understood by the individual designated in 35 U.S.C. §1.56(c) most knowledgeable about the content of the information, the undersigned attorney of record submits a translation of portions of an official action by a foreign examiner in which the reference was cited. The relevance to the pending U.S. patent application is that the reference was cited in a foreign patent application on the same subject matter. However, no independent analysis of the reference, the accuracy of the statement of the foreign examiner or the claims of the foreign application under the laws of that country or the United States relative to the subject matter claimed in the present application has been made, the present understanding of the contents thereof by the undersigned being based on the translation of the foreign examiner's comments submitted herewith.

This citation does not constitute an admission that the references are relevant or material to the claims. They are only cited as constituting related art of which the applicants are aware.

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I hereby certify that each item of information contained in this Information Disclosure Statement was the first citation of that item by a foreign patent office in a counterpart foreign application, which occurred not more than three months prior to the filing of this statement.

It is respectfully requested that the listed references be considered by the Examiner and formally made of record in this application.

Please charge any deficiencies in fees and credit any overpayment of fees to Attorney's Deposit Account No. 50-0481.

Respectfully submitted,

Scott M. Tulino, Esq. Registration No. 48,317

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Date: July 6, 2005
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INFORMATION DISCLOSURE CITATION (Use several sheets if necessary)					Docket Number (Optional) F03-354-USDiv		Application Number 10/634,836		
					Applicant(s) Hisaki KATO, et al.				
					Filing Date		Group Art Unit		
					August 6, 20	03	2822		
			U.S.	PATENT	DOCUMENTS				
EXAMINER	REF	DOCUMENT NUMBER	DATE	NAME		CLASS	SUBCLASS	FILING DATE	
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		TRADEMARKS.							
			U.S. PATENT	APPLICA	ATION PUBLICATIONS	<u> </u>			
EXAMINER INITIAL REF		DOCUMENT NUMBER	DATE		NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE	
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		LT OSS A stion		DOCUMEN	partial English translation		Pertinent Pages, E	же.)	
		Japanese Office Action,	dated May 24, 2	,005, WILII	partial English translati	U11			
		NAKAMURA, et al., "R September 2, 1996, Vol.	Ridge-geometry I 69, No. 10, pp. 1	InGaN mu 1477-1479	lti-quantum-well-structu	ire laser diode	s", APPLIED P	HYŚICS L	ETTERS,
EXAMIN	ER			. · · · ·	DATE CONSIDERED				

Form PTO-A820 (also form PTO-1449)

not considered. Include copy of this form with next communication to applicant.

P09A/REV05

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and

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